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 Functionally Equivalent to QS3244 Standard '244-Type Pinout 	DB, DBQ, DGV, DW, OR PW PACKAGE (TOP VIEW)
 25-Ω Switch Connection Between Two Ports 	10E 1 20 V <u>CC</u> 1A1 2 19 20E
TTL-Compatible Input Levels	2B4 🛛 3 18 🖸 1B1
 Package Options Include Plastic 	1A2 4 17 2A4
Small-Outline (DW), Shrink Small-Outline	2B3 5 16 1B2
(DB, DBQ), Thin Very Small-Outline (DGV),	1A3 4 6 15 2A3
and Thin Shrink Small-Outline (PW)	2B2 7 14 1B3
Packages	1A4 🛛 8 13 🖸 2A2
	2B1 🛛 9 12 🗍 1B4
description	GND [10 11] 2A1

The SN74CBTR3244 provides eight bits of high-speed TTL-compatible bus switching in a standard '244 device pinout. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

The device is organized as two 4-bit low-impedance switches with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the switch is on, and data can flow from port A to port B, or vice versa. When \overline{OE} is high, the switch is open, and a high-impedance state exists between the two ports.

The device has equivalent 25- Ω series resistors to reduce signal-reflection noise. This eliminates the need for external terminating resistors.

The SN74CBTR3244 is characterized for operation from -40°C to 85 °C.

(each 4-bit bus switch)					
INPUT OE	FUNCTION				
L	A port = B port				
н	Disconnect				

FUNCTION TABLE



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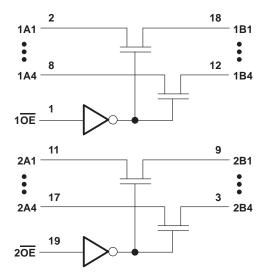
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logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC}	
Input voltage range, V _I (see Note 1)	
Continuous channel current	
Clamp current, $I_K (V_{I/O} < 0)$	
Package thermal impedance, θ_{JA} (see Note 2):	DB package
	DBQ package 68°C/W
	DGV package
	DW package
	PW package 83°C/W
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 3)

		MIN	MAX	UNIT
VCC	Supply voltage	4.5	5.5	V
VIH	High-level control input voltage	2		V
VIL	Low-level control input voltage		0.8	V
Τ _Α	Operating free-air temperature	0	70	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

P	ARAMETER		TEST CONDI	TIONS	MIN	түр†	MAX	UNIT
VIK		V _{CC} = 4.5 V,	lı = –18 mA				-1.2	V
Ц		V _{CC} = 5.5 V,	$V_{I} = 5.5 \text{ V or GND}$				±5	μΑ
ICC		V _{CC} = 5.5 V,	I _O = 0,	$V_I = V_{CC}$ or GND			50	μΑ
∆lcc‡	Control inputs	V _{CC} = 5.5 V,	One input at 3.4 V,	Other inputs at V_{CC} or GND			3.5	mA
Ci	Control inputs	$V_I = 3 V \text{ or } 0$						pF
Cio(OFF	=)	$V_{O} = 3 V \text{ or } 0,$	$\overline{OE} = V_{CC}$					pF
r _{on} §		$V_{CC} = 4.5 V$	V _I = 0	lj = 64 mA				
				II = 30 mA				Ω
			V _I = 2.4 V,	lj = 15 mA				

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡]This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

§ Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

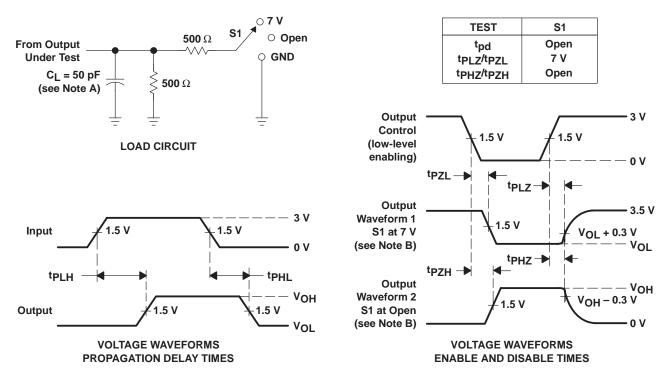
switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	МАХ	UNIT
t _{pd} ¶	A or B	B or A			ns
ten	OE	A or B			ns
^t dis	OE	A or B			ns

The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. CL includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_Q = 50 Ω, t_r ≤ 2.5 ns. t_f ≤ 2.5 ns.

D. The outputs are measured one at a time with one transition per measurement.

E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .

F. tpzL and tpzH are the same as t_{en} .

G. tPLH andtPHL are the same as tpd.





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